



MEMS Variable Optical Attenuator

Description

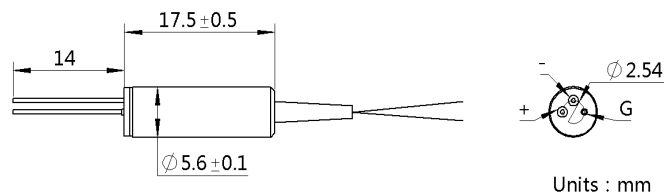
Rev 11B

AFR's MEMS Variable Optical Attenuator is based on an electrostatic driven micro-electro-mechanical-system (MEMS) chip. The MEMS chip consists of a tilting mirror to change light coupling between input and output fibers. The components are characterized with low insertion loss, fast response and compact size. It is widely used in WDM networks, power control or gain variation in EDFA.

Specifications

Parameter	Unit	Value
Operating Wavelength Range	nm	1530 - 1570/1570 - 1610
Insertion Loss	dB	≤ 0.8
Attenuation Range	dB	> 30
Block State (Dark type, IL at power off)	dB	> 40
Polarization Dependence Loss@ 0 dB	dB	≤ 0.1
Polarization Dependence Loss@ 20 dB	dB	≤ 0.3
Wavelength Dependence Loss@ 10 dB	dB	≤ 0.5
Wavelength Dependence Loss@ 20 dB	dB	≤ 1.0
Ripple(within 0.4nm window within 20 dB)	dB	≤ 0.05
Polarization Mode Dispersion (PMD)	ps	≤ 0.1
Return Loss	dB	> 45
Response Time	ms	≤ 2
Max. Optical Power (Continuous Wave)	mW	300
Drive Voltage	V	≤ 8
Fiber Type	-	SMF-28
Operating Temperature	°C	- 5 to + 70
Storage Temperature	°C	- 40 to + 85

Package Dimensions



Ordering Information

MEMSVOA-①-②-③-④-⑤

①: Wavelength	②: VOA Type	③: Connector Type	④: Fiber Jacket	⑤: Fiber Length
C - C Band	D - Dark	1 - FC/UPC	B - 250 μm Bare Fiber	1 - 1.0 m
L - L Band	B - Bright	2 - FC/APC	L - 900 μm Loose Tube	S - Specify
		3 - SC/UPC	S - Specify	
		4 - SC/APC		
		N - None		
		S - Specify		